

UNITED STATES PATENT AND TRADEMARK OFFICE
CERTIFICATE OF CORRECTION

PATENT NO. : 6,914,017 B1
APPLICATION NO. : 09/651790
DATED : July 5, 2005
INVENTOR(S) : Baluswamy et al.

Page 1 of 1

It is certified that error appears in the above-identified patent and that said Letters Patent is hereby corrected as shown below:

On the Title page, in field (54), in "Title", in column 1, line 1, delete "RESIDUE FREE OVERLAY TARGET" and insert -- RAISED-LINES OVERLAY SEMICONDUCTOR TARGETS AND METHOD OF MAKING THE SAME --, therefor.

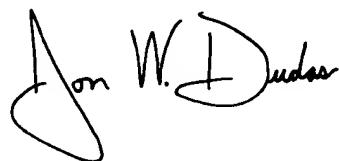
On the Title page, in field (56), under "U.S. Patent Documents", in column 1, line 5, below "5,786,260 A 7/1998 Jang et al." insert -- 5,841,144 11/1998 Cresswell --.

On the Title page, in field (57), under "Abstract", in column 2, line 2, delete "residue-residue free" and insert -- residue free --, therefor.

In column 1, line 1, delete "RESIDUE FREE OVERLAY TARGET" and insert -- RAISED-LINES OVERLAY SEMICONDUCTOR TARGETS AND METHOD OF MAKING THE SAME --, therefor.

Signed and Sealed this

Twenty Second Day of April, 2008



JON W. DUDAS
Director of the United States Patent and Trademark Office